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June 2005

FDS4685 40V P-Channel PowerTrench[®] MOSFET



FDS4685 40V P-Channel PowerTrench[®] MOSFET

Features

- -8.2 A, -40 V $R_{DS(ON)} = 0.027 \Omega @ V_{GS} = -10 V R_{DS(ON)} = 0.035 \Omega @ V_{GS} = -4.5 V$
- Fast switching speed
- High performance trench technology for extremely low R_{DS(ON)}
- High power and current handling capability

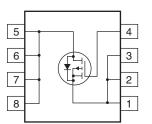
Applications

- Power management
- Load switch
- Battery protection

General Description

This P-Channel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications requiring a wide range of gate drive voltage ratings (4.5V - 20V).





Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-Source Voltage		-40	V	
V _{GSS}	Gate-Source Voltage		±20	V	
I _D	Drain Current - Continuous	(Note 1a)	-8.2	A	
	- Pulsed		-50		
P _D	D Power Dissipation for Single Operation		2.5	W	
		(Note 1b)	1.4		
		(Note 1c)	1.2		
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C	
Thermal Ch	aracteristics				
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W	
R _{θJA}	Thermal Resistance, Junction-to-Ambient	(Note 1c)	125		
R _{0JC}	Thermal Resistance, Junction-to-Case	(Note 1)	25		

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS4685	FDS4685	13"	12mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Charac	teristics		1			
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$				V
$\Delta BV_{DSS} \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-32		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -32 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Charac	teristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-1	-1.6	-3	V
$\begin{array}{c} \Delta V_{\text{GS(th)}} \\ \Delta T_J \end{array}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		4.7		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -8.2 \text{ A}$ $V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -7 \text{ A}$ $V_{GS} = -10 \text{ V}, \text{ I}_{D} = -8.2 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C}$		22 29 31	27 35 42	mΩ
9 _{FS}	Forward Transconductance	$V_{DS} = -5 V, I_D = -8.2 A$		22		S
Dynamic C	haracteristics		1			
C _{iss}	Input Capacitance	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V},$		1872		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		256		pF
C _{rss}	Reverse Transfer Capacitance			134		pF
R _G	Gate Resistance	$V_{GS} = 15 \text{ mV}, \text{ f} = 1 \text{MHz}$		4		Ω
Switching	Characteristics (Note 2)	·				
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -20 \text{ V}, \text{ I}_{D} = -1 \text{ A},$		14	25	ns
t _r	Turn–On Rise Time	$V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		11	20	ns
t _{d(off)}	Turn-Off Delay Time			50	80	ns
t _f	Turn–Off Fall Time			18	32	ns
Qg	Total Gate Charge	$V_{DS} = -20 \text{ V}, \text{ I}_{D} = -8.2 \text{ A},$		19	27	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -5 V$		5.6		nC
Q _{gd}	Gate-Drain Charge			6.1		nC
Drain-Sou	rce Diode Characteristics					
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V, I_S = -2.1 A (Note 2)$		-0.7	-1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_{\rm F} = -8.2 {\rm A},$		26		nS
Q _{rr}	Diode Reverse Recovery Charge	$d_{iF}/d_t = 100 \text{ A}/\mu\text{s}$		15		nC

Electrical Characteristics T - 25°C unloss otherwise noted

Notes:

1. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BJC} is guaranteed by design while R_{BCA} is determined by the user's board design.



a) 50°C/W when mounted on a 1 in² pad of 2 oz

b) 105°/W when mounted on a .04 in² pad of 2 oz copper ωψψμ

c) 125°/W when mounted on a minimum pad.

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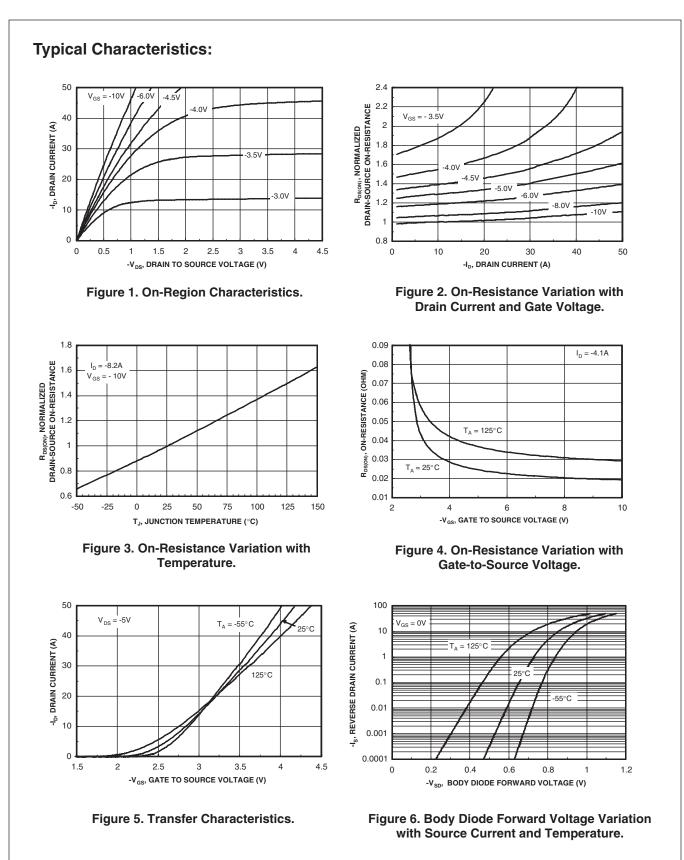
YY YY

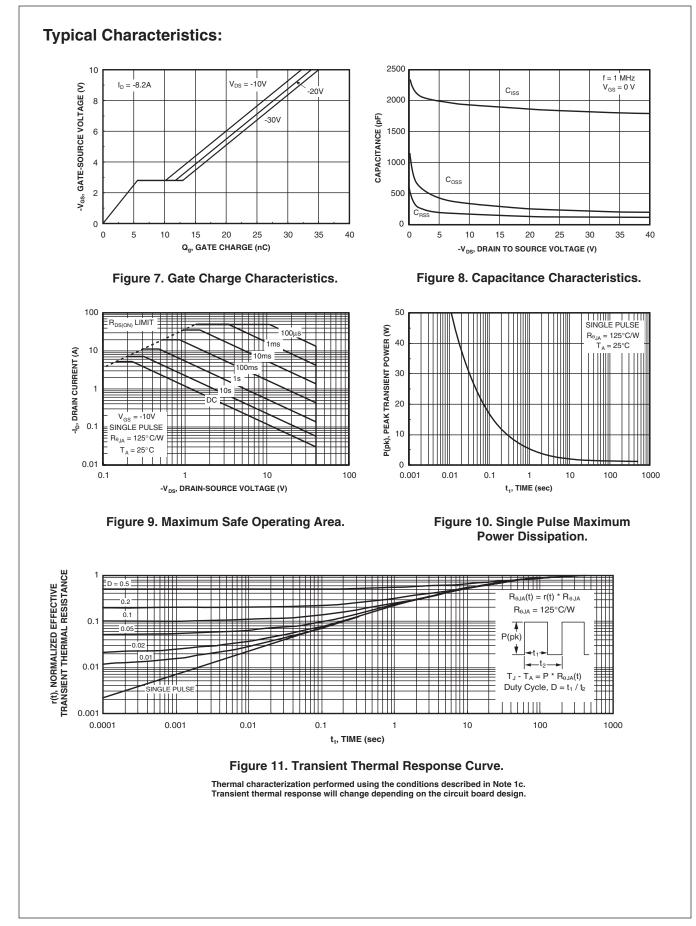
Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

copper

FDS4685 40V P-Channel PowerTrench[®] MOSFET





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Definition of Terms

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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